

## HMIC™ Silicon PIN Diode SP3T Switch 50 MHz - 20 GHz

Rev. V3

### Features

- Operates 50 MHz to 20 GHz
- Usable up to 26 GHz
- Low Insertion Loss
- High Isolation
- Low Parasitic Capacitance and Inductance
- RoHS Compliant Surmount Package
- Rugged, Fully Monolithic
- Glass Encapsulated Construction
- Up to +38 dBm CW Power Handling @ +25°C
- Silicon Nitride Passivation
- Polymer Scratch Protection
- Solderable

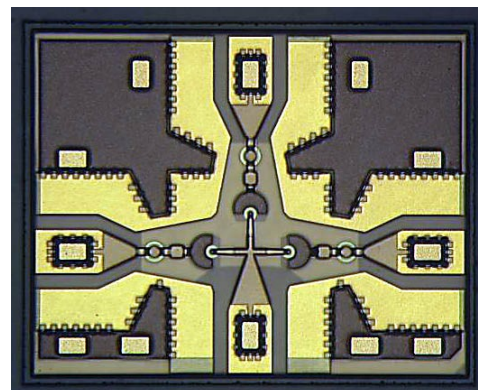
### Description

The MASW-003103-1364 is a SP3T, surmount, broadband, monolithic switch using series and shunt connected silicon PIN diodes. This device is designed for use in broadband, moderate signal, high performance, switch applications up to 20 GHz. It is a surface mountable switch configured for optimized performance and offers a distinct advantage over MMIC, beamlead and chip and wire hybrid designs. Because the PIN diodes of the MASW-004103-1365 are integrated into the chip and kept within close proximity, the parasitics typically associated with other designs that use individual components are kept to a minimum.

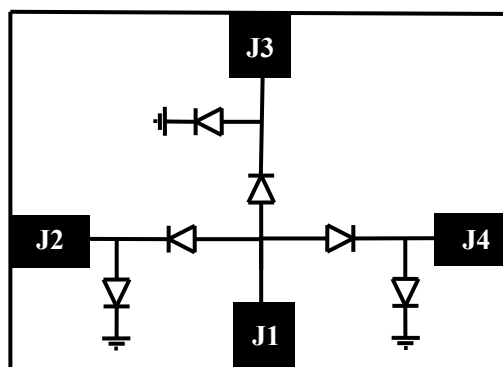
To minimize the parasitics and achieve high performance the MASW-003103-1364 is fabricated using MACOMs' patented HMIC™ (Heterolithic Microwave Integrated Circuit) process. This process allows the silicon pedestals, which form the series and shunt diodes or vias, to be imbedded in low loss, low dispersion glass. The combination of low loss glass and using tight spacing between elements results in an HMIC device with low loss and high isolation through low millimeter wave frequencies.

The topside is fully encapsulated with silicon nitride and also has an additional layer of polymer for scratch and impact protection. The protective coating guards against damage to the junction and the anode airbridges during handling and assembly.

On the backside of the chip gold metalized pads have been added to produce a solderable surmount device.



### Functional Schematic



### Pin Configuration

| Pin | Function |
|-----|----------|
| J1  | RFC      |
| J2  | RF1      |
| J3  | RF2      |
| J4  | RF3      |

### Ordering Information

| Part #             | Package           |
|--------------------|-------------------|
| MASW-003103-13640G | 50 piece gel pack |
| MASW-003103-13645P | 500 piece reel    |
| MASW-003103-13640P | 3000 piece reel   |
| MASW-003103-001SMB | Sample Test Board |

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Rev. V3

**Electrical Specifications:**  $T_A = 25^\circ\text{C}$ ,  $P_{IN} = 0\text{ dBm}$ ,  $Z_0 = 50\ \Omega$ , 20 mA, -10 V

| Parameter                      | Conditions | Units | Min. | Typ. | Max. |
|--------------------------------|------------|-------|------|------|------|
| Insertion Loss                 | 6 GHz      | dB    | —    | 0.5  | 0.6  |
|                                | 13 GHz     |       |      | 0.8  | 1.1  |
|                                | 20 GHz     |       |      | 1.2  | 1.4  |
| Isolation                      | 6 GHz      | dB    | 50   | 54   | —    |
|                                | 13 GHz     |       | 37   | 40   |      |
|                                | 20 GHz     |       | 25   | 31   |      |
| Input Return Loss              | 6 GHz      | dB    | 19   | 25   | —    |
|                                | 13 GHz     |       | 14   | 22   |      |
|                                | 20 GHz     |       | 14   | 21   |      |
| Output to Output Isolation     | 6 GHz      | dB    | —    | 57   | —    |
|                                | 13 GHz     |       |      | 42   |      |
|                                | 20 GHz     |       |      | 30   |      |
| Input 0.1 dB Compression Point | 2 GHz      | dBm   | —    | 36   | —    |
| Switching Speed <sup>1</sup>   | —          | ns    | —    | 20   | —    |
| Voltage Rating <sup>2</sup>    | —          | V     | —    | —    | 80   |

1. Typical Switching Speed measured from 10% to 90 % of detected RF signal driven by TTL compatible drivers.
2. Maximum reverse leakage current in either the shunt or series PIN diodes shall be 0.5  $\mu\text{A}$  maximum @ -80 volts.

### Absolute Maximum Ratings<sup>3,4,5</sup>

| Parameter                               | Absolute Maximum |
|-----------------------------------------|------------------|
| RF CW Incident Power<br>2 GHz<br>20 GHz | 38 dBm<br>33 dBm |
| Applied Reverse Voltage                 | [-80 V]          |
| Bias Current +25°C                      | ± 50 mA          |
| Junction Temperature                    | +175°C           |
| Operating Temperature                   | -65°C to +125°C  |
| Storage Temperature                     | -65°C to +150°C  |

3. Exceeding any one or combination of these limits may cause permanent damage to this device.
4. MACOM does not recommend sustained operation near these survivability limits.
5. Combined maximum operating conditions for RF power, DC bias, & temperature: 33 dBm CW, 20 mA per diode, +85°C.

### Handling Procedures

Please observe the following precautions to avoid damage:

### Static Sensitivity

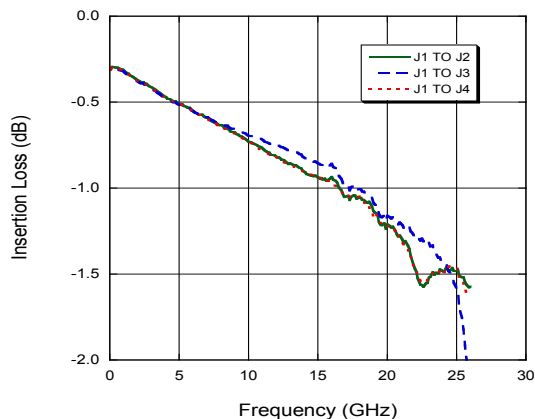
These electronic devices are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these Class 1A HBM devices.

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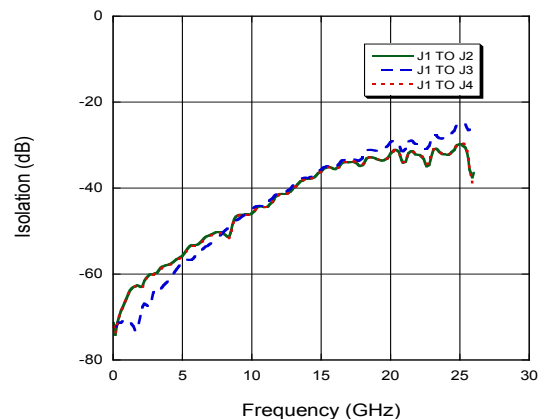
Rev. V3

### Typical Performance Curves: 20 mA, -10 V (On-Wafer Probed)

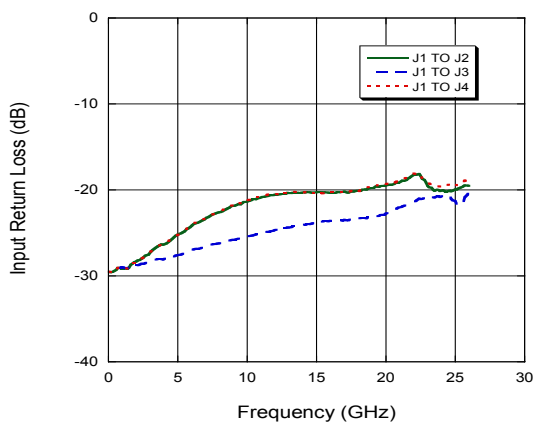
**Insertion Loss**



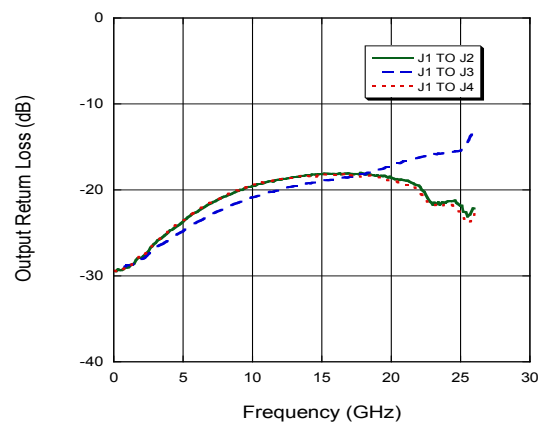
**Isolation**



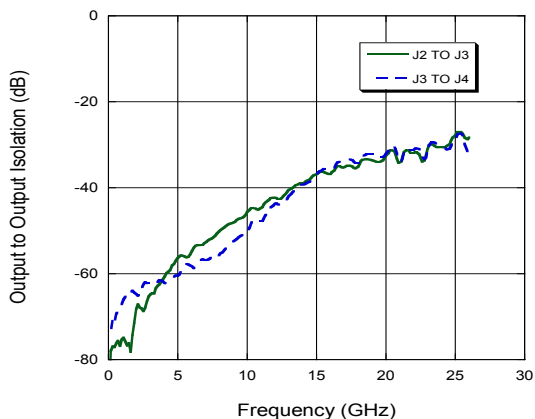
**Input Return Loss**



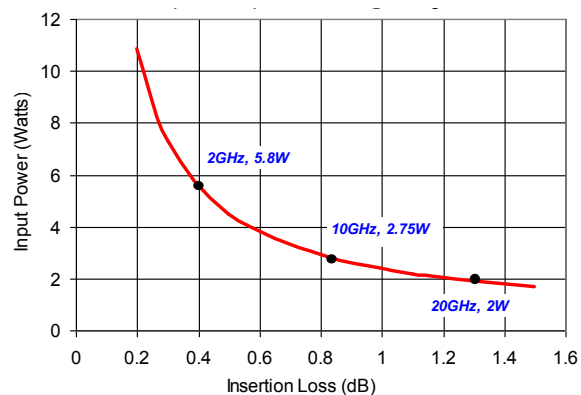
**Output Return Loss**



**Output to Output Isolation**



**Maximum Input Power,  
Baseplate Temperature fixed @ +25°C**



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Rev. V3

### Bias Control

Optimal operation of the MASW-003103-1364 is achieved by simultaneous application of negative DC voltage and current to the low loss switching arm J2, J3, or J4, and positive DC voltage and current to the remaining switching arms as shown in the applications circuit below. DC return is achieved via R2 on the J1/RF Com Path.

In the low loss state, the series diode must be forward biased with current and the shunt diode reverse biased with voltage. In the isolation arms, the shunt diode is forward biased with current and the series diode is reverse biased with voltage.

### Driver Connections

| Control Level (DC Currents and Voltages) |                              |                              | Condition of RF Output |           |           |
|------------------------------------------|------------------------------|------------------------------|------------------------|-----------|-----------|
| B2                                       | B3                           | B4                           | J1-J2                  | J1-J3     | J1-J4     |
| -15 V at -20 mA <sup>5</sup>             | +6 V at +20 mA               | +6 V at +20 mA               | Low Loss               | Isolation | Isolation |
| +6 V at +20 mA                           | -15 V at -20 mA <sup>5</sup> | +6 V at +20 mA               | Isolation              | Low Loss  | Isolation |
| +6 V at +20 mA                           | +6 V at +20 mA               | -15 V at -20 mA <sup>5</sup> | Isolation              | Isolation | Low Loss  |

5. The voltage applied to the off arm is allowed to vary provided a constant current is applied through the shunt diode on the off arm.

### Application Circuit<sup>6,7,8,9,10</sup>

#### Example:

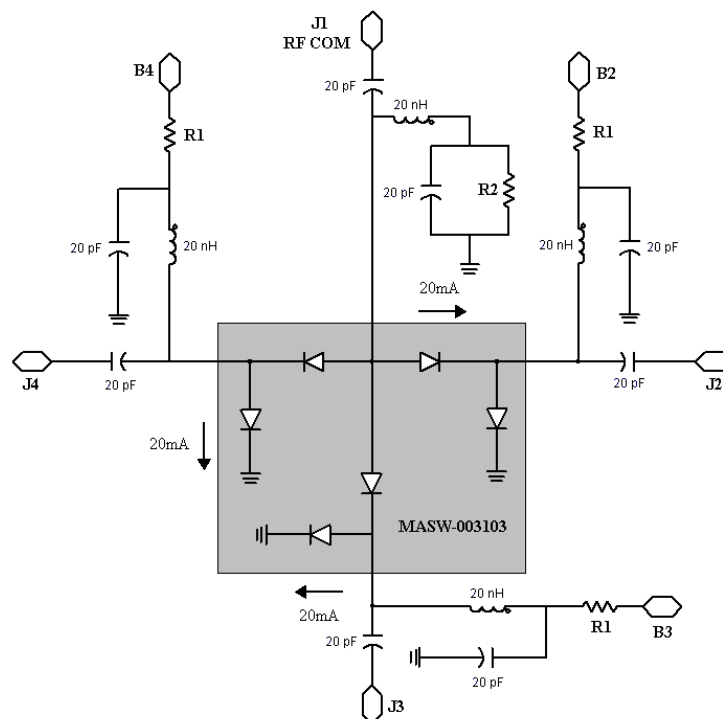
J1 to J2 → Low Loss

R1 = 250 Ω

R2 = 450 Ω

B2 = -15 V

B3, B4 = 6 V



6. Assume  $V_F \sim 1 \text{ V @ } 20 \text{ mA}$

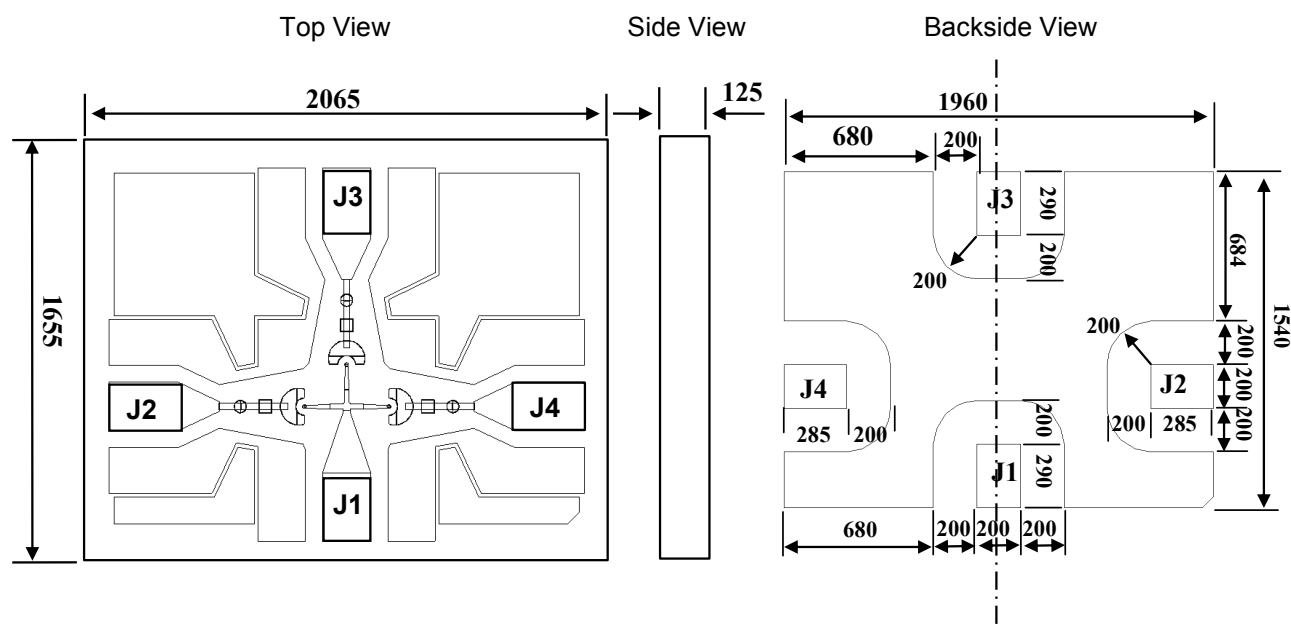
7.  $R1 = 5 \text{ V} / 0.02 \text{ A} = 250 \text{ } \Omega$ ;  $R2 = 9 \text{ V} / 0.02 \text{ A} = 450 \text{ } \Omega$

8.  $P_{R1} = 0.02 \text{ A} \times 0.02 \text{ A} \times 250 = 0.1 \text{ W}$

9.  $P_{R2} = 0.02 \text{ A} \times 0.02 \text{ A} \times 450 = 0.18 \text{ W}$

10. Inductors shown in the above schematic are RF bias chokes. The operating bandwidth of a broad-band PIN diode switch is often dependent on the bias components, particularly the RF bias chokes. It is suggested that the response at the frequencies of interest be measured with all the bias components in place prior to installing of MASW-003103-1364.

## Outline Drawing and Footprint (All dimensions in $\mu\text{m}$ )<sup>11,12,13,14</sup>



11. Bottom view shows the back metal foot print and mounting pads.
12. All dimension are  $\pm 0.5 \mu\text{m}$ .
13. Ground radius is 200  $\mu\text{m}$  and centered on the I/O Pad.
14. The center pad shown on the chip bottom view must be connected to RF and DC ground.

## Dimensions

| Dim.      | Inches  |         | mm    |       |
|-----------|---------|---------|-------|-------|
|           | Min.    | Max.    | Min.  | Max.  |
| Width     | 0.06417 | 0.06614 | 1.630 | 1.680 |
| Length    | 0.08031 | 0.08228 | 2.040 | 2.090 |
| Thickness | 0.00394 | 0.00591 | 0.100 | 0.150 |

## Handling Procedures

Attachment to a circuit board is made simple through the use of standard surface mount technology. Mounting pads are conveniently located on the bottom surface of these devices and are removed from the active junction locations. These devices are well suited for solder attachment onto hard and soft substrates. The use of 80Au/20Sn, or RoHS compliant solders is recommended. For applications where the average power is  $\leq 1W$ , conductive silver epoxy may also be used. Cure per manufacturers recommended time and temperature. Typically 1 hour at 150°C.

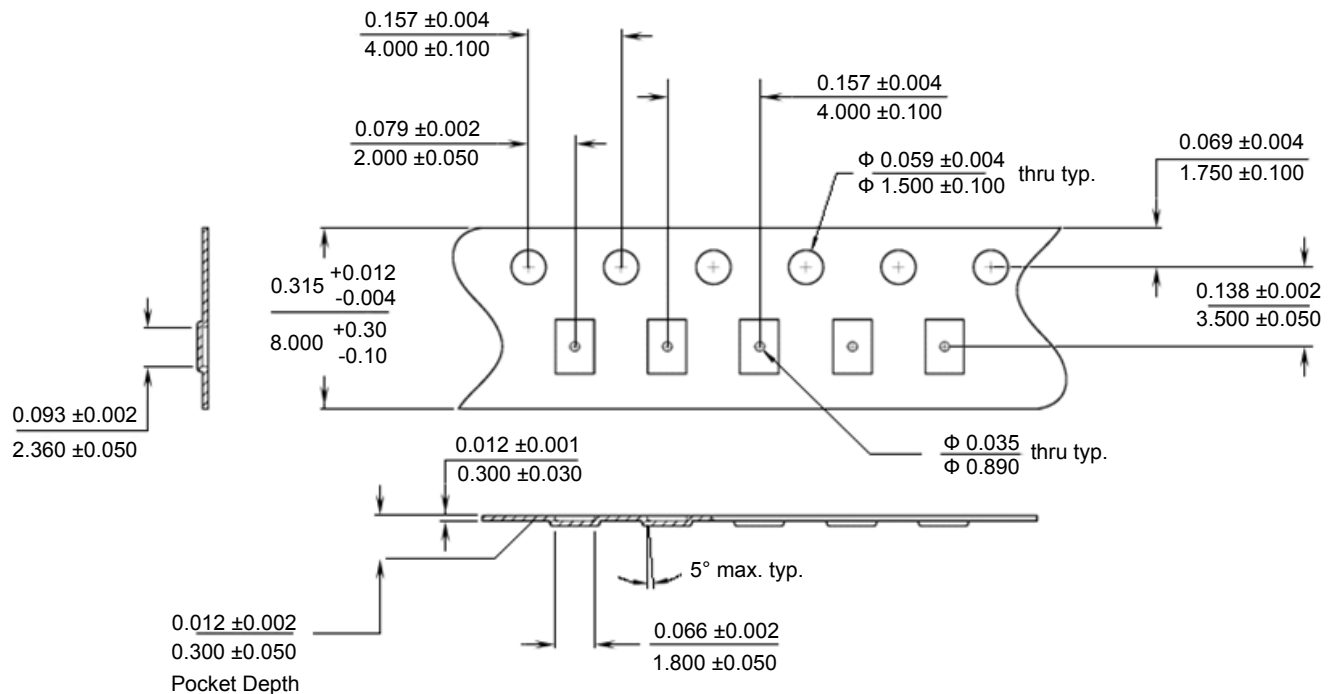
When soldering these devices to a hard substrate, a solder re-flow method is preferred. A vacuum tip pick-up tool and a force of 60 to 100 grams applied to the top surface of the device while placing the chip is recommended. When soldering to soft substrates, such as Duroid, it is recommended to use a soft solder at the circuit board to mounting pad interface to minimize stress due to any TCE mismatches that may exist. Position the die so that its mounting pads are aligned with the circuit board mounting pads. Solder reflow should not be performed by causing heat to flow through the top surface of the die to the back. Since the HMIC glass is transparent, the edges of the mounting pads can be visually inspected through the die after attachment is completed.

Typical re-flow profiles for Sn60/Pb40 and RoHS compliant solders is provided in Application Note M538, "Surface Mounting Instructions" and can be viewed on the MACOM Technology Solutions website @ [www.macom.com](http://www.macom.com)

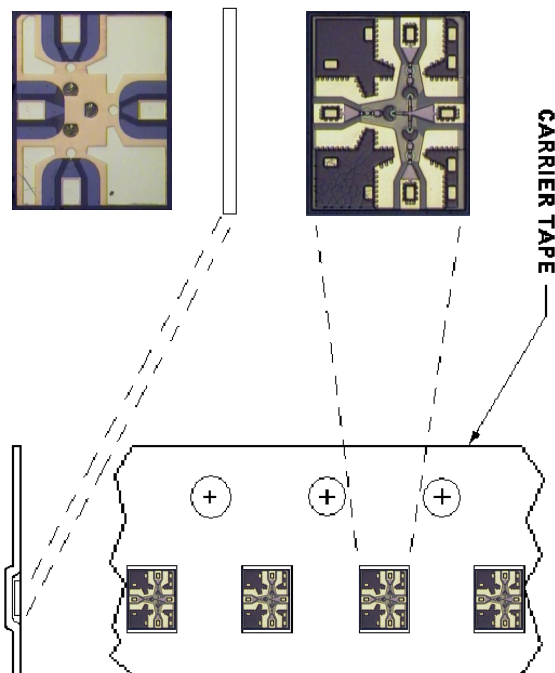
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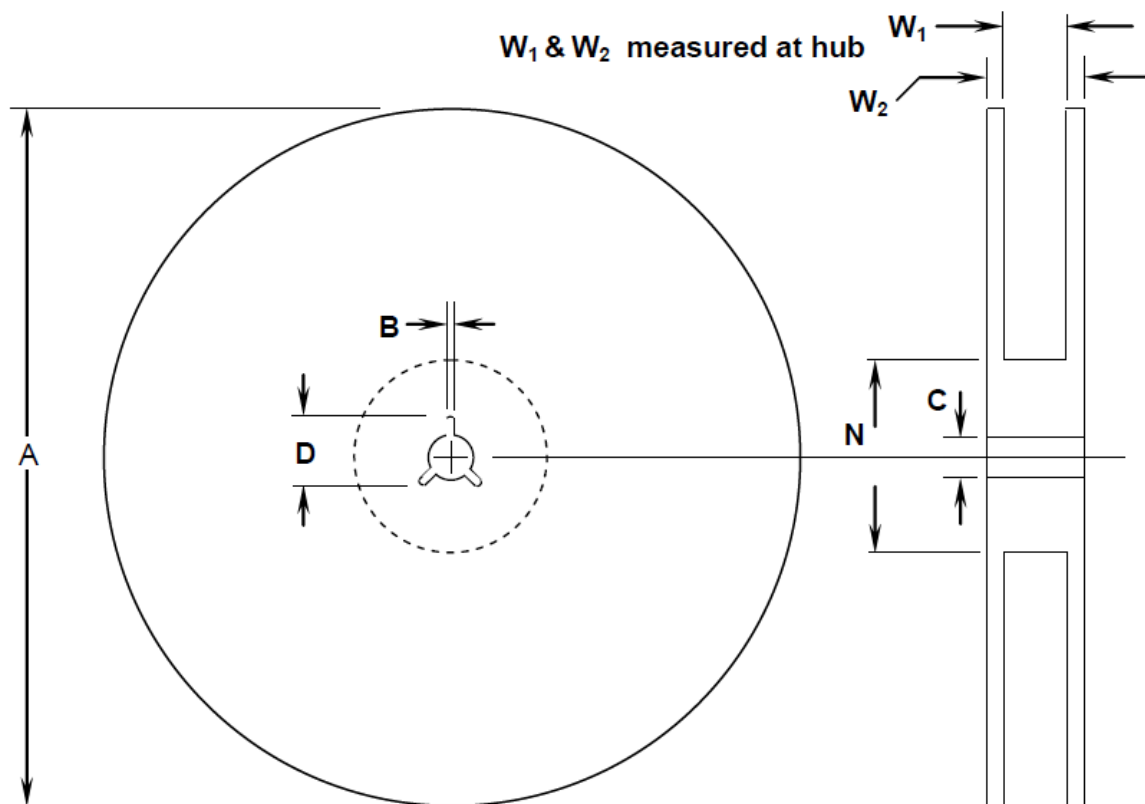
### Carrier Tape Dimensions



### Chip Orientation in Tape



## Reel Information



| Dim.           | inches |       | mm    |       |
|----------------|--------|-------|-------|-------|
|                | Min.   | Max.  | Min.  | Max.  |
| A              | 6.980  | 7.019 | 177.3 | 178.3 |
| B              | 0.059  | 0.098 | 1.5   | 2.5   |
| C              | 0.504  | 0.520 | 12.8  | 13.2  |
| D              | 0.795  | 0.815 | 20.2  | 20.7  |
| N              | 2.146  | 2.185 | 54.5  | 55.5  |
| W <sub>1</sub> | 0.331  | 0.337 | 8.4   | 8.55  |
| W <sub>2</sub> | —      | 0.567 | —     | 14.4  |

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